

* Per Leg, ** Per Device

C3D20065D

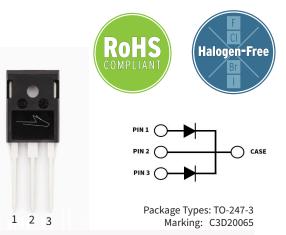
3rd Generation 650 V, 20 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.

Features

- High-Frequency Operation
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior
- Parallel Devices Without Thermal Runaway



Applications

- Boost Diodes in PFC or DC/DC Stages
- Free Wheeling Diodes in Inverter Stages
- Switch Mode Power Supplies
- Solar Inverters
- AC/DC Converters

Maximum Ratings ($T_c = 25^{\circ}C$ Unless Otherwise Specified)

Symbol Value Unit **Test Conditions Parameter** Notes **Repetitive Peak Reverse Voltage** 650 V_{RRM} V_{RSM} 650 V Surge Peak Reverse Voltage **DC Blocking Voltage** V_{DC} 650 T_c = 25 °C 27.5/55 **Continuous Forward Current** ١_ 13/26 T_c = 135 °C Fig. 3 (Per Leg/Per Device) 10/20 $T_{c} = 149 \,^{\circ}C$ 46* $T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Wave}$ **Repetitive Peak Forward Surge** Current 31* А $T_c = 110 \text{ °C}, t_n = 10 \text{ ms}, \text{Half Sine Wave}$ 90* $T_c = 25 \text{ °C}, t_n = 10 \text{ ms}, \text{Half Sine Wave}$ Non-Repetitive Forward Surge Fig. 8 I_{ESM} Current 71* $T_c = 110$ °C, $t_n = 10$ ms, Half Sine Wave 860* $T_{c} = 25 \text{ °C}, t_{p} = 10 \text{ } \mu \text{s}, \text{Pulse}$ Non-Repetitive Peak Forward l _{F,Max} Surge Current 680* $T_{c} = 110 \text{ °C}, t_{p} = 10 \text{ }\mu\text{s}, \text{Pulse}$ 115.5/231 T_c = 25 °C **Power Dissipation** $\mathsf{P}_{\rm tot}$ W Fig. 4 (Per Leg/Per Device) 50/100 $T_{c} = 110 \ ^{\circ}C$ Diode dV/dt Ruggedness dV/dt 200 $V_{p} = 0.650V$ V/ns

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Electrical Characteristics

| Parameter | Symbol | Тур. | Max. | Unit | Test Conditions | Notes |
|---------------------------|----------------|-------|------|------|---|---------|
| | | 1.5 | 1.8 | v | I _F = 10 A, T _j = 25 °C | - Fi- 1 |
| Forward Voltage | V _F | 2.0 | 2.4 | V | I _F = 10 A, T _j = 175 °C | Fig. 1 |
| Deverse Comment | I _R | 12 | 60 | μA | V _R = 650 V, T _j = 25 °C | Fig. 2 |
| Reverse Current | | 24 | 220 | | V _R = 650 V, T _j = 175 °C | |
| Total Capacitive Charge | Q _c | 24 | | nC | $V_{R} = 400 V, T_{j} = 25 °C$ $I_{F} = 10A, di/dt = 500A/\mu s$ | Fig. 5 |
| | | 460.5 | | | $V_{R} = 0 V, T_{j} = 25 °C, f = 1 MHz$ | |
| Total Capacitance | С | 44 | | pF | $V_{R} = 200 \text{ V}, \text{ T}_{j} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$ | Fig. 6 |
| | | 40 | | | $V_{R} = 400 \text{ V}, \text{ T}_{j} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$ | |
| Capacitance Stored Energy | E _c | 3.6 | | μJ | V _R = 400 V | Fig. 7 |

Notes:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

| Parameter | Symbol | Value | Unit | Notes |
|--|----------------------|----------------|--------|------------|
| Thermal Resistance, Junction to Case (Typical) | $R_{\theta,JC(TYP)}$ | 1.3** 0.65* | °C / W | |
| Junction Temperature | Tj | -55 to +175 | - °C - | |
| Case & Storage Temperature | T _c | -55 to +175 | | |
| | | 1 | Nm | M3 Screw |
| TO-247 Mounting Torque | - | 8.8 | lbf-in | 6-32 Screw |

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Typical Performance

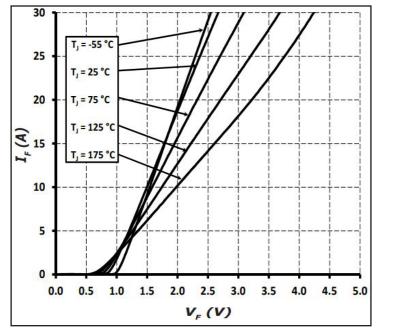


Figure 1 Forward Characteristics

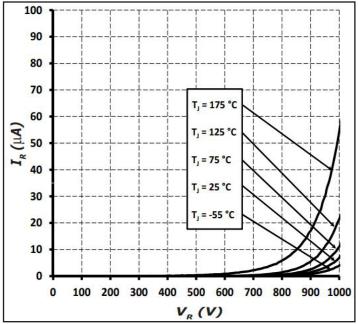
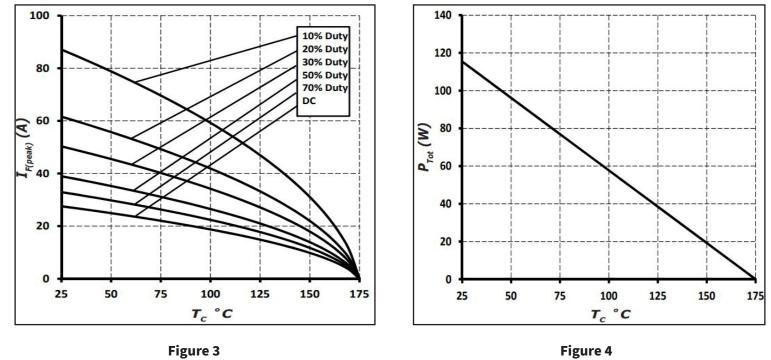


Figure 2 Reverse Characteristics



Current Derating



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Typical Performance

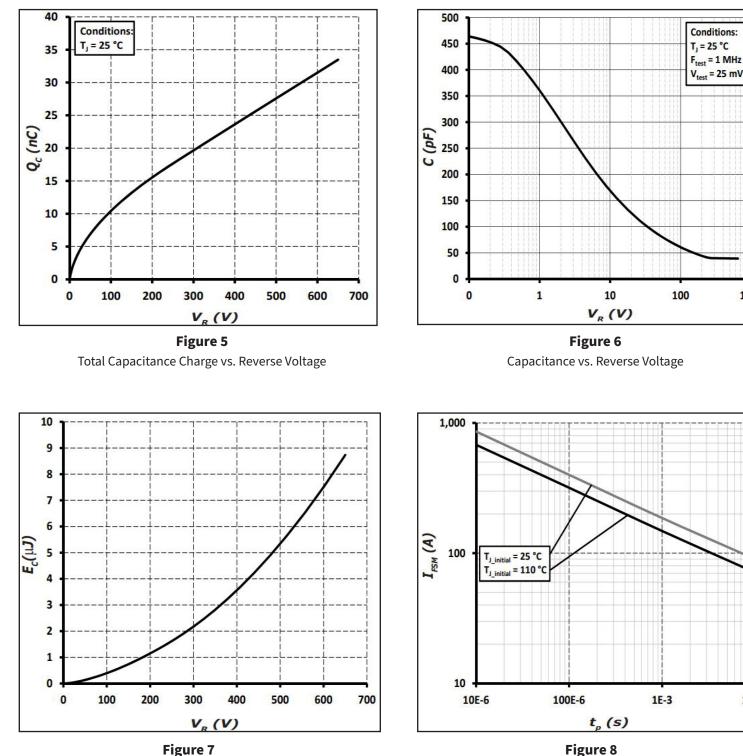


Figure 7 Capacitance Stored Energy

Non-Repetitive Peak Forward Surge Current vs. Pulse Duration

4

1000

10E-3

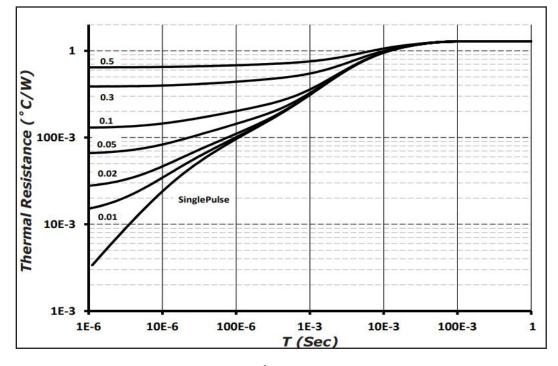
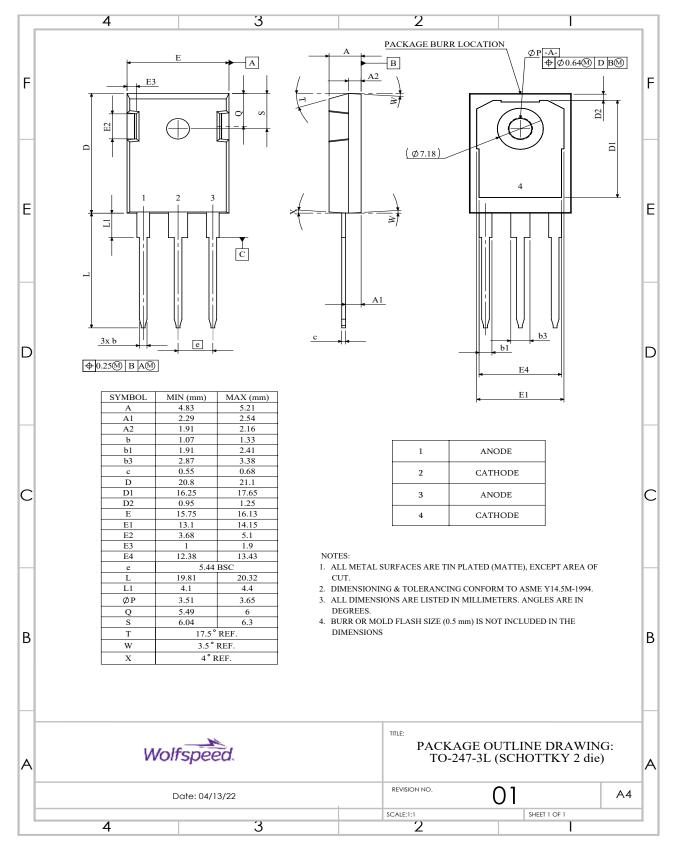


Figure 9 Transient Thermal Impedance

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Package Dimensions & Pin-Out

Package: TO-247-3



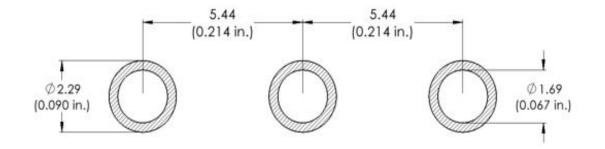
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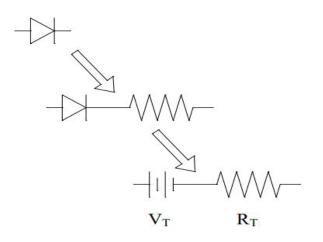
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Recommended Solder Pad Layout

Primary dimensions shown in mm.



Diode Model



| $Vf_T = V_T + If * R_T$ |
|--|
| 0.94 + (T」* -1.3*10 ⁻³) 0.044 + (T」* 4.4*10 ⁻⁴) |

Note: T_j = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

Product Ordering Information

| Order Number | Packing Type | |
|--------------|--------------|--|
| C3D20065D | Tube | |

REACh, RoHS, and Halogen-Free compliance documentation available for this product.

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Revision History

| Document Version | Date of Release | Description of Changes | |
|------------------|-----------------|---|--|
| 3 | May- 2021 | Initial Release | |
| 4 | November-2023 | Update Branding, POD, Package Image, Solder pad layout | |



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